

ROITHNER LASERTECHNIK

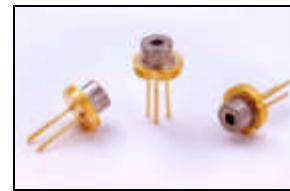
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S6305MG

TECHNICAL DATA



Visible Wavelength Laserdiode

Structure: InGaAlP, index guided single transverse mode

Lasing wavelength: 635 nm typ.

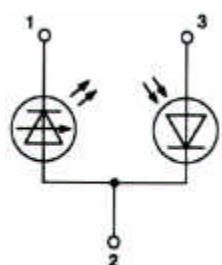
Output power: 5 mW, CW

Package: 5.6 mm, TO-18

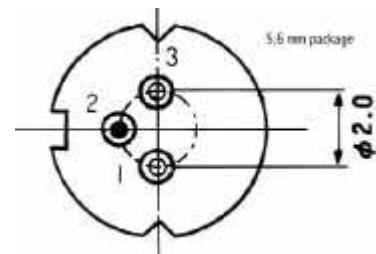


NOTE!
LASERDIODE
MUST BE COOLED!

PIN CONNECTION:



- 1) Laser diode cathode
- 2) Laser diode anode and photodiode cathode
- 3) Photodiode anode



Maximum Ratings (Tc=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Optical Output Power	P _o	7	mW
LD Reverse Voltage	V _{R(LD)}	2	V
PD Reverse Voltage	V _{R(PD)}	30	V
Operation Case Temperature	T _C	-10 .. +40	°C
Storage Temperature	T _{STG}	-40 .. +85	°C

Optical-Electrical Characteristics (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Threshold Current	I _{th}	cw		35	45	mA
Operation Current	I _{op}	P _o = 5 mW		45	60	mA
Operating Voltage	V _{op}	P _o = 5 mW	2.1	2.3	2.6	V
Lasing Wavelength	λ _p	P _o = 5 mW	630	635	640	nm
Beam Divergence	θ	P _o = 5 mW	6	7.5	9	°
Beam Divergence	θ _⊥	P _o = 5 mW	32	38	42	°
Slope Efficiency	η	P _o = 3 mW	0.35	0.55	0.8	mW/mA
Monitor Current	I _m	P _o = 5 mW	100	250	650	μA
Deviation Angle	Δθ	P _o = 5 mW			±5	°
Deviation Angle	Δθ _⊥	P _o = 5 mW			±5	°
Emission Point Accuracy	Δx	-			±80	μm
	Δy	-			±80	μm
	Δz	-			±80	μm